

TOSHIBA GTR MODULE SILICON N CHANNEL IGBT

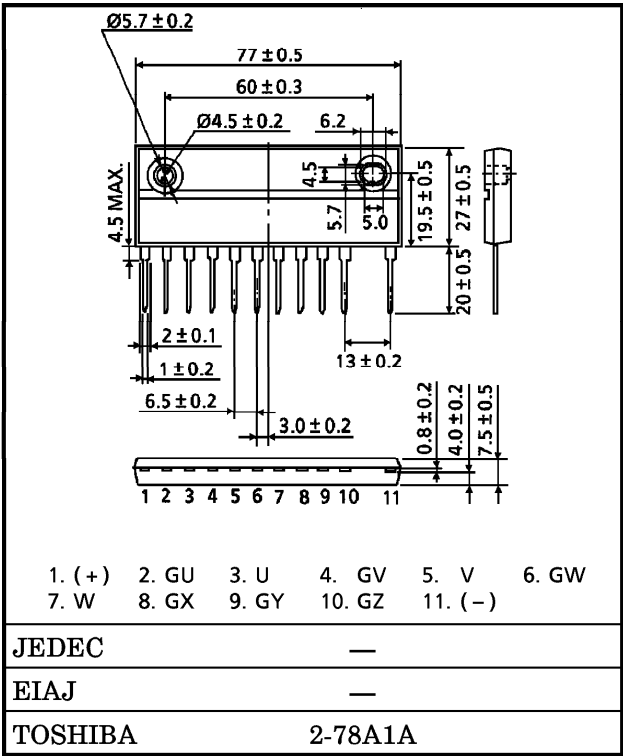
MP6759

MOTOR CONTROL APPLICATIONS

Unit in mm

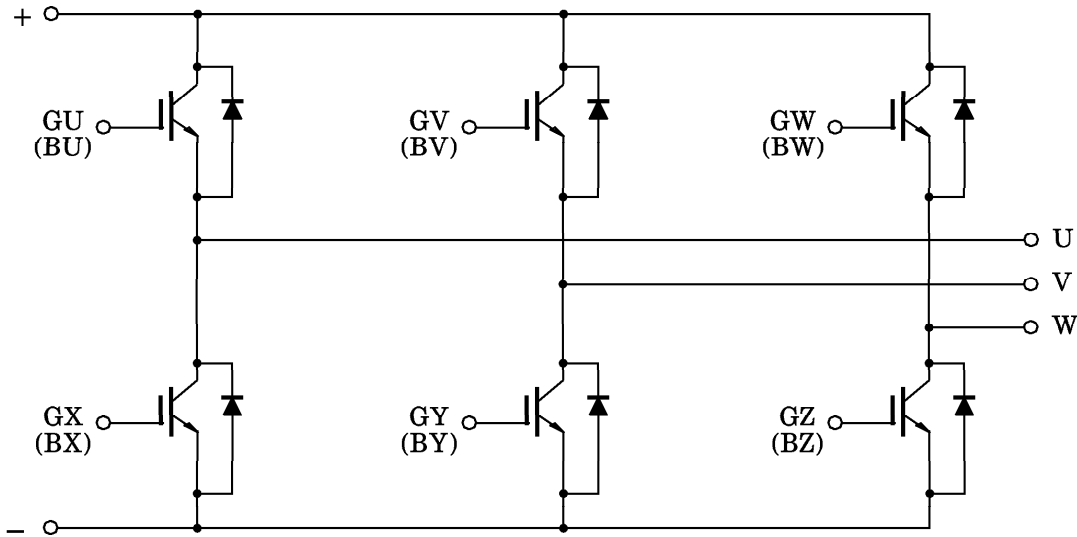
HIGH POWER SWITCHING APPLICATIONS

- The Electrodes are Isolated from Case.
- 6 IGBTs are Built Into 1 Package.
- Enhancement-Mode
- Low Saturation Voltage  
:  $V_{CE(sat)} = 2.7\text{ V (Max.) (I_C = 10\text{ A})}$
- High Speed  
:  $t_f = 0.35\text{ }\mu\text{s (Max.) (I_C = 10\text{ A})}$



Weight : 44 g (Typ.)

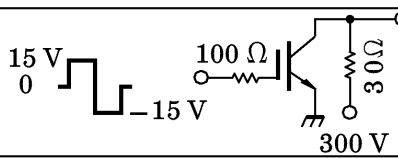
EQUIVALENT CIRCUIT

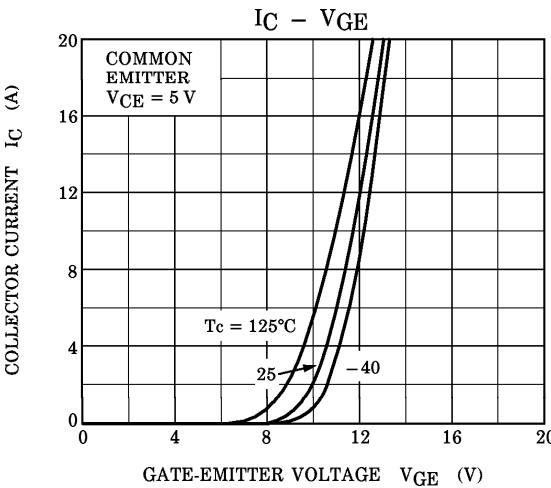
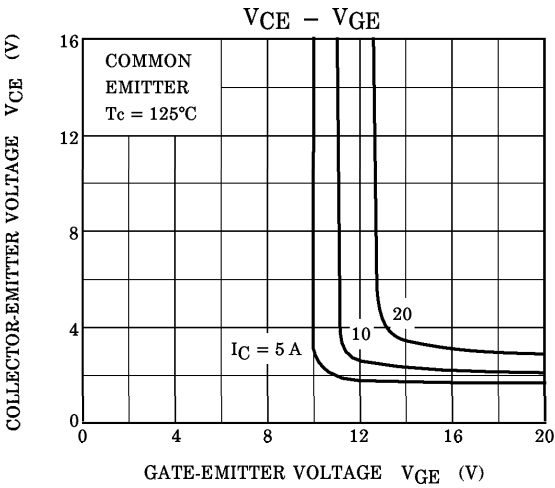
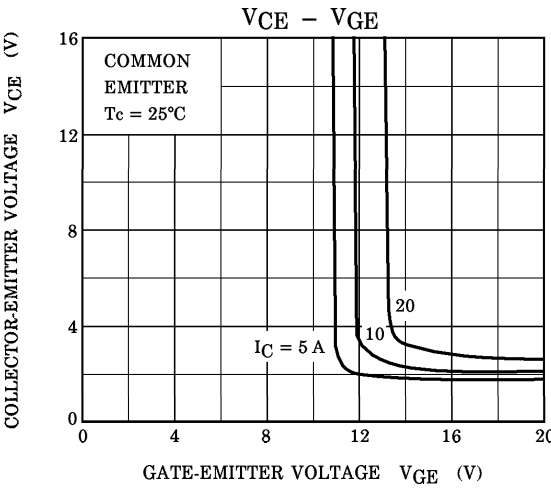
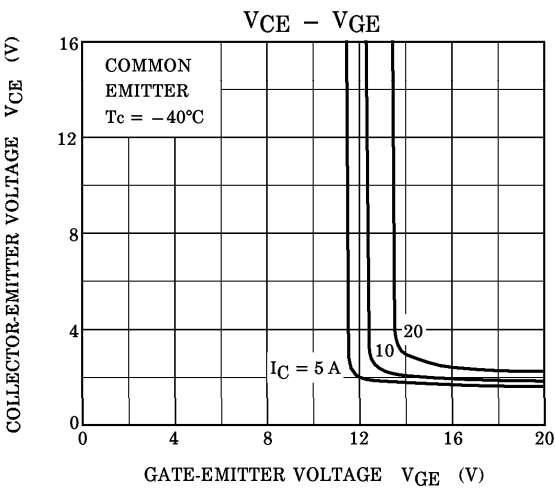
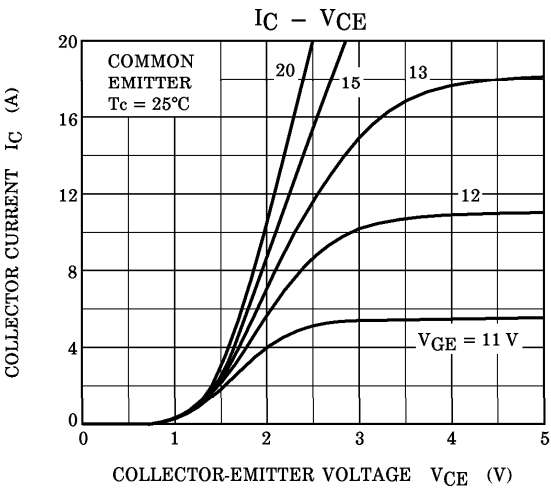


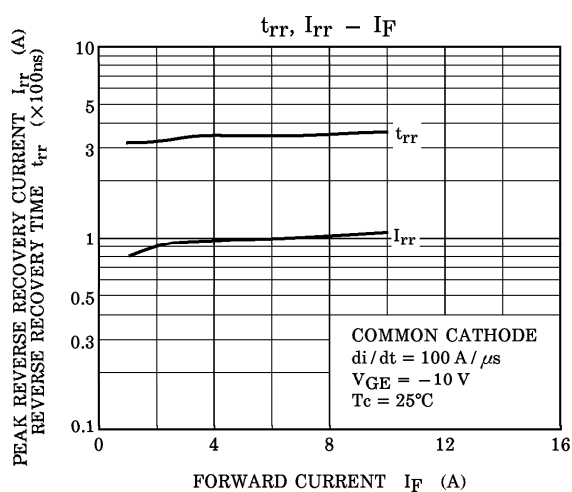
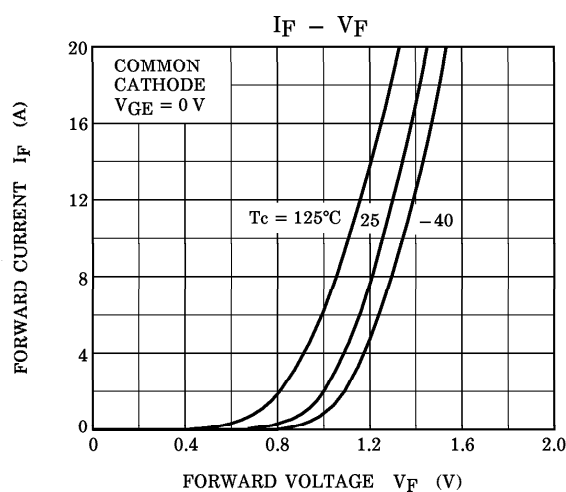
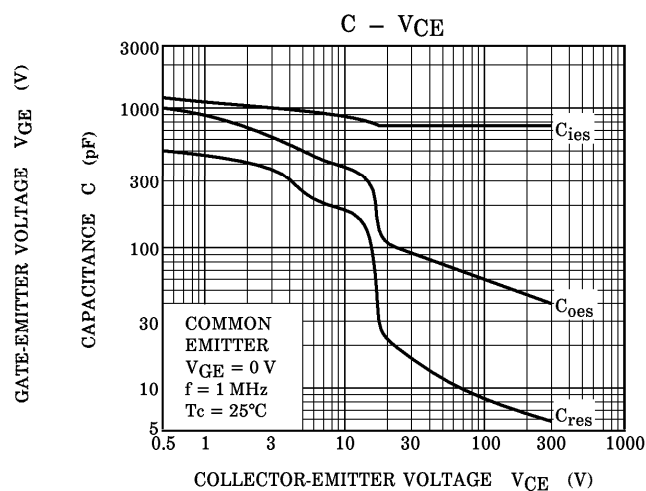
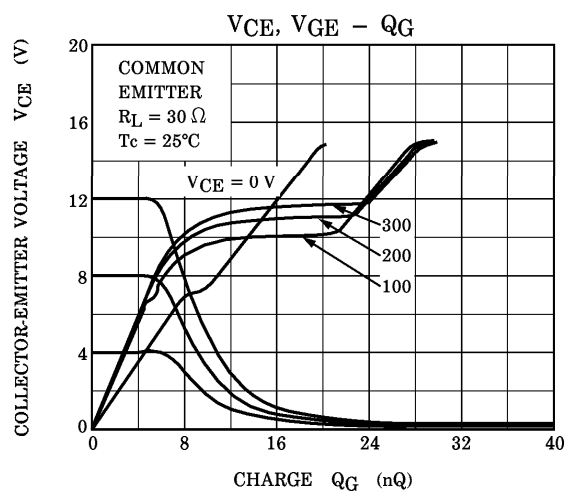
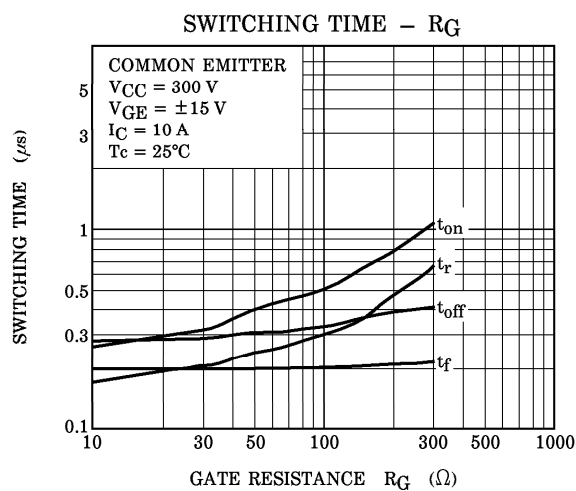
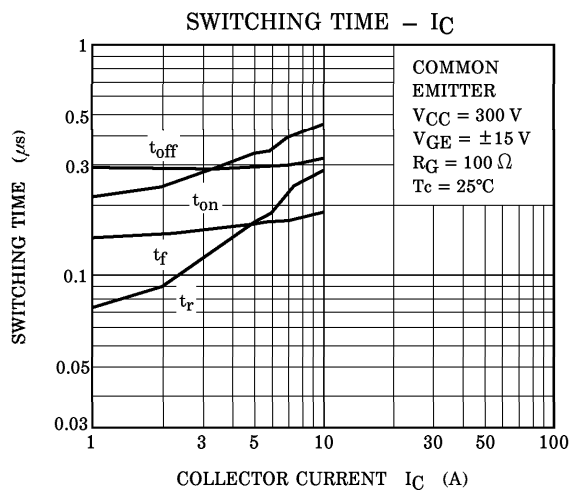
## MAXIMUM RATINGS (Ta = 25°C)

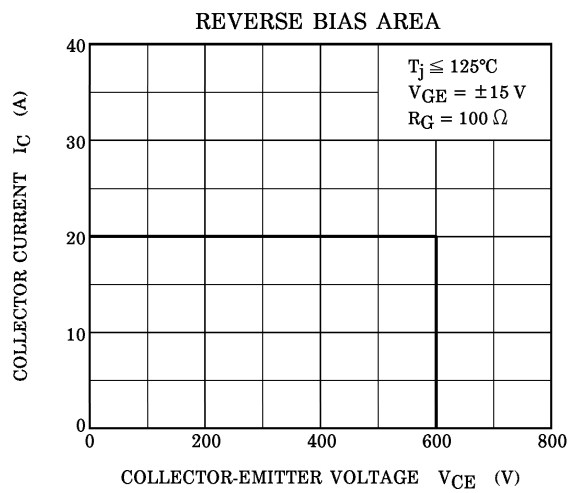
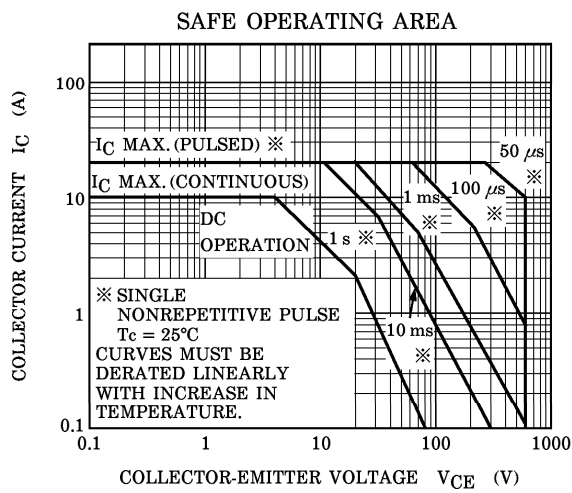
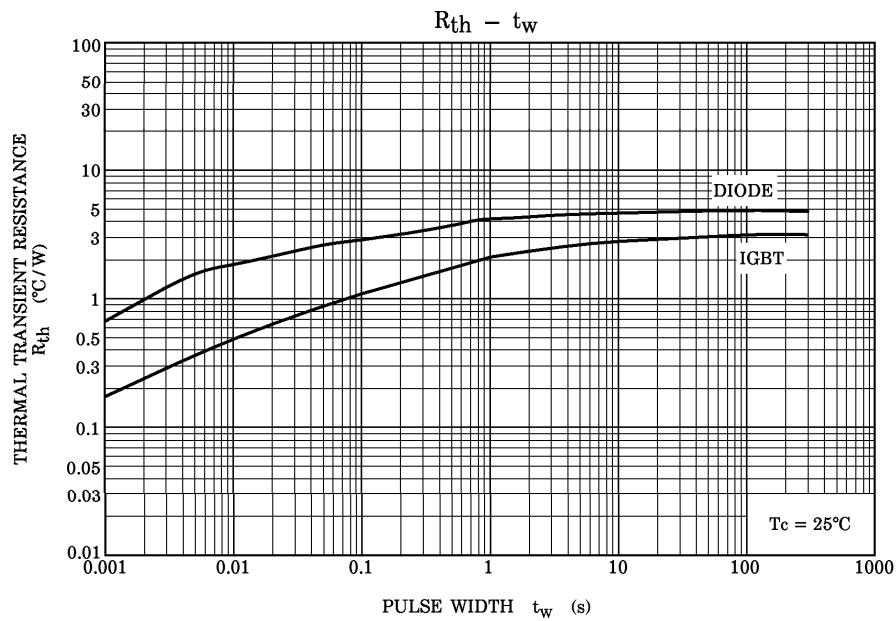
CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Emitter Voltage		V <sub>CES</sub>	600	V
Gate-Emitter Voltage		V <sub>GES</sub>	±20	V
Collector Current	DC	I <sub>C</sub>	10	A
	1 ms	I <sub>CP</sub>	20	
Forward Current	DC	I <sub>F</sub>	10	A
	1 ms	I <sub>FM</sub>	20	
Collector Power Dissipation (T <sub>c</sub> = 25°C)		P <sub>C</sub>	40	W
Junction Temperature		T <sub>j</sub>	150	°C
Storage Temperature Range		T <sub>stg</sub>	−40~125	°C
Isolation Voltage		V <sub>ISOL</sub>	2500 (AC 1 minute)	V
Screw Torque		—	1.5	N·m

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current		I <sub>GES</sub>	V <sub>GE</sub> = ±20 V, V <sub>CE</sub> = 0	—	—	±200	nA
Collector Cut-off Current		I <sub>CES</sub>	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0	—	—	1	mA
Gate-Emitter Cut-off Voltage		V <sub>GE (OFF)</sub>	I <sub>C</sub> = 1 mA, V <sub>CE</sub> = 5 V	5	—	8	V
Collector-Emitter Saturation Voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 10 A, V <sub>GE</sub> = 15 V	—	2.1	2.7	V
Input Capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10 V, V <sub>GE</sub> = 0, f = 1 MHz	—	720	—	pF
Switching Time	Rise Time	t <sub>r</sub>		—	0.3	—	μs
	Turn-on Time	t <sub>on</sub>		—	0.4	—	
	Fall Time	t <sub>f</sub>		—	0.2	0.35	
	Turn-off Time	t <sub>off</sub>		—	0.4	—	
Forward Voltage		V <sub>F</sub>	I <sub>F</sub> = 10 A, V <sub>GE</sub> = 0	—	—	2.0	V
Reverse Recovery time		t <sub>rr</sub>	I <sub>F</sub> = 10 A, di/dt = −100 A/μs	—	—	200	ns
Thermal Resistance	R <sub>th (j-c)</sub>	Transistor		—	—	3.09	°C/W
		Diode		—	—	4.77	







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